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Understanding <u>Embedded - FPGAs (Field Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Obsolete
Number of LABs/CLBs	768
Number of Logic Elements/Cells	-
Total RAM Bits	-
Number of I/O	69
Number of Gates	12000
Voltage - Supply	3V ~ 3.6V, 4.75V ~ 5.25V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 70°C (TA)
Package / Case	84-LCC (J-Lead)
Supplier Device Package	84-PLCC (29.31x29.31)
Purchase URL	https://www.e-xfl.com/product-detail/microsemi/a54sx08-pl84

Email: info@E-XFL.COM

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Chip Architecture

The SX family chip architecture provides a unique approach to module organization and chip routing that delivers the best register/logic mix for a wide variety of new and emerging applications.

Module Organization

Actel has arranged all C-cell and R-cell logic modules into horizontal banks called *clusters*. There are two types of *clusters*: Type 1 contains two C-cells and one R-cell, while Type 2 contains one C-cell and two R-cells.

To increase design efficiency and device performance, Actel has further organized these modules into *SuperClusters* (Figure 1-4). SuperCluster 1 is a two-wide grouping of Type 1 clusters. SuperCluster 2 is a two-wide group containing one Type 1 cluster and one Type 2 cluster. SX devices feature more SuperCluster 1 modules than SuperCluster 2 modules because designers typically require significantly more combinatorial logic than flip-flops.

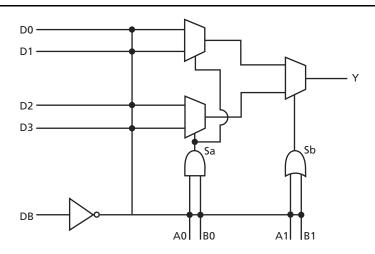


Figure 1-3 • C-Cell

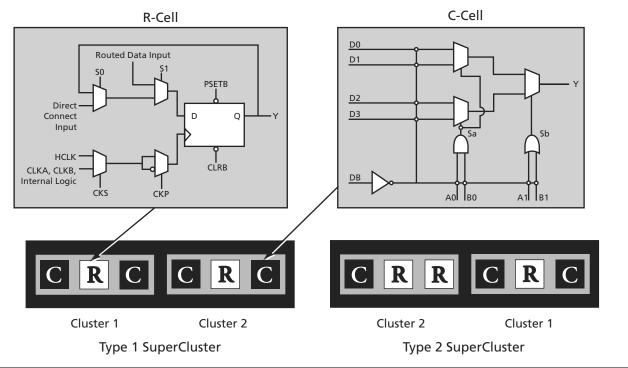


Figure 1-4 • Cluster Organization

DirectConnect is a horizontal routing resource that provides connections from a C-cell to its neighboring R-cell in a given SuperCluster. DirectConnect uses a hardwired signal path requiring no programmable interconnection to achieve its fast signal propagation time of less than 0.1 ns.

FastConnect enables horizontal routing between any two logic modules within a given SuperCluster and vertical routing with the SuperCluster immediately below it. Only one programmable connection is used in a FastConnect path, delivering maximum pin-to-pin propagation of 0.4 ns.

In addition to DirectConnect and FastConnect, the architecture makes use of two globally oriented routing resources known as segmented routing and high-drive routing. The Actel segmented routing structure provides a variety of track lengths for extremely fast routing between SuperClusters. The exact combination of track lengths and antifuses within each path is chosen by the 100 percent automatic place-and-route software to minimize signal propagation delays.

The Actel high-drive routing structure provides three clock networks. The first clock, called HCLK, is hardwired from the HCLK buffer to the clock select multiplexer (MUX) in each R-cell. This provides a fast propagation path for the clock signal, enabling the 3.7 ns clock-to-out (pin-to-pin) performance of the SX devices. The hardwired clock is tuned to provide clock skew as low as 0.25 ns. The remaining two clocks (CLKA, CLKB) are global clocks that can be sourced from external pins or from internal logic signals within the SX device.

Other Architectural Features

Technology

The Actel SX family is implemented on a high-voltage twin-well CMOS process using 0.35 μ design rules. The metal-to-metal antifuse is made up of a combination of amorphous silicon and dielectric material with barrier metals and has a programmed ("on" state) resistance of 25 Ω with a capacitance of 1.0 fF for low signal impedance.

Performance

The combination of architectural features described above enables SX devices to operate with internal clock frequencies exceeding 300 MHz, enabling very fast execution of even complex logic functions. Thus, the SX family is an optimal platform upon which to integrate the functionality previously contained in multiple CPLDs. In addition, designs that previously would have required a gate array to meet performance goals can now be integrated into an SX device with dramatic improvements in cost and time to market. Using timingdriven place-and-route tools, designers can achieve highly deterministic device performance. With SX devices, designers do not need to use complicated performance-enhancing design techniques such as the use of redundant logic to reduce fanout on critical nets or the instantiation of macros in HDL code to achieve high performance.

I/O Modules

Each I/O on an SX device can be configured as an input, an output, a tristate output, or a bidirectional pin.

Even without the inclusion of dedicated I/O registers, these I/Os, in combination with array registers, can achieve clock-to-out (pad-to-pad) timing as fast as 3.7 ns. I/O cells that have embedded latches and flip-flops require instantiation in HDL code; this is a design complication not encountered in SX FPGAs. Fast pin-to-pin timing ensures that the device will have little trouble interfacing with any other device in the system, which in turn enables parallel design of system components and reduces overall design time.

Power Requirements

The SX family supports 3.3 V operation and is designed to tolerate 5.0 V inputs. (Table 1-1). Power consumption is extremely low due to the very short distances signals are required to travel to complete a circuit. Power requirements are further reduced because of the small number of low-resistance antifuses in the path. The antifuse architecture does not require active circuitry to hold a charge (as do SRAM or EPROM), making it the lowest power architecture on the market.

Table 1-1 • Supply Voltages

Device	V _{CCA}	V _{CCI}	V _{CCR}	Maximum Input Tolerance	Maximum Output Drive
A54SX08 A54SX16 A54SX32	3.3 V	3.3 V	5.0 V	5.0 V	3.3 V
A54SX16-P*	3.3 V	3.3 V	3.3 V	3.3 V	3.3 V
	3.3 V	3.3 V	5.0 V	5.0 V	3.3 V
	3.3 V	5.0 V	5.0 V	5.0 V	5.0 V

Note: *A54SX16-P has three different entries because it is capable of both a 3.3 V and a 5.0 V drive.

Boundary Scan Testing (BST)

All SX devices are IEEE 1149.1 compliant. SX devices offer superior diagnostic and testing capabilities by providing Boundary Scan Testing (BST) and probing capabilities. These functions are controlled through the special test pins in conjunction with the program fuse. The functionality of each pin is described in Table 1-2. In the dedicated test mode, TCK, TDI, and TDO are dedicated pins and cannot be used as regular I/Os. In flexible mode, TMS should be set HIGH through a pull-up resistor of $10~\mathrm{k}\Omega$. TMS can be pulled LOW to initiate the test sequence.

The program fuse determines whether the device is in dedicated or flexible mode. The default (fuse not blown) is flexible mode.

Table 1-2 ● **Boundary Scan Pin Functionality**

Program Fuse Blown (Dedicated Test Mode)	Program Fuse Not Blown (Flexible Mode)
TCK, TDI, TDO are dedicated BST pins.	TCK, TDI, TDO are flexible and may be used as I/Os.
No need for pull-up resistor for TMS	Use a pull-up resistor of 10 k Ω on TMS.

Dedicated Test Mode

In Dedicated mode, all JTAG pins are reserved for BST; designers cannot use them as regular I/Os. An internal pull-up resistor is automatically enabled on both TMS and TDI pins, and the TMS pin will function as defined in the IEEE 1149.1 (JTAG) specification.

To select Dedicated mode, users need to reserve the JTAG pins in Actel's Designer software by checking the "Reserve JTAG" box in "Device Selection Wizard" (Figure 1-7). JTAG pins comply with LVTTL/TTL I/O specification regardless of whether they are used as a user I/O or a JTAG I/O. Refer to the Table 1-5 on page 1-8 for detailed specifications.

Figure 1-7 • Device Selection Wizard

Development Tool Support

The SX family of FPGAs is fully supported by both the Actel Libero® Integrated Design Environment (IDE) and Designer FPGA Development software. Actel Libero IDE is a design management environment, seamlessly integrating design tools while guiding the user through the design flow, managing all design and log files, and passing necessary design data among tools. Libero IDE allows users to integrate both schematic and HDL synthesis into a single flow and verify the entire design in a single environment. Libero IDE includes Synplify® for Actel from Synplicity[®], ViewDraw[®] for Actel from Mentor Graphics[®], ModelSim[®] HDL Simulator from Mentor Graphics, WaveFormer Lite™ SynaptiCAD™, and Designer software from Actel. Refer to the Libero IDE flow diagram (located on the Actel website) for more information.

Actel Designer software is a place-and-route tool and provides a comprehensive suite of backend support tools for FPGA development. The Designer software includes timing-driven place-and-route, and a world-class integrated static timing analyzer and constraints editor. With the Designer software, a user can select and lock package pins while only minimally impacting the results of place-and-route. Additionally, the back-annotation flow is compatible with all the major simulators, and the simulation results can be cross-probed with Silicon Explorer II, Actel integrated verification and logic analysis tool. Another tool included in the Designer software is the SmartGen core generator, which easily creates popular and commonly used logic functions for implementation into your schematic or HDL design. Actel Designer software is compatible with the most popular FPGA design entry and verification tools from companies such as Mentor Graphics, Synplicity, Synopsys[®], and Cadence® Design Systems. The Designer software is available for both the Windows® and UNIX® operating systems.

Probe Circuit Control Pins

The Silicon Explorer II tool uses the boundary scan ports (TDI, TCK, TMS, and TDO) to select the desired nets for verification. The selected internal nets are assigned to the PRA/PRB pins for observation. Figure 1-8 on page 1-7 illustrates the interconnection between Silicon Explorer II and the FPGA to perform in-circuit verification.

Design Considerations

The TDI, TCK, TDO, PRA, and PRB pins should not be used as input or bidirectional ports. Because these pins are active during probing, critical signals input through these pins are not available while probing. In addition, the Security Fuse should not be programmed because doing so disables the Probe Circuitry.

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Table 1-4 • Recommended Operating Conditions

Parameter	Commercial	Industrial	Military	Units
Temperature Range*	0 to + 70	-40 to + 85	-55 to +125	°C
3.3 V Power Supply Tolerance	±10	±10	±10	%V _{CC}
5.0 V Power Supply Tolerance	±5	±10	±10	%V _{CC}

Note: *Ambient temperature (T_A) is used for commercial and industrial; case temperature (T_C) is used for military.

Table 1-5 ● **Electrical Specifications**

		Comm	ercial	Indus	trial	
Symbol	Parameter	Min.	Мах.	Min.	Max.	Units
V _{OH}	(I _{OH} = -20 μA) (CMOS)	(V _{CCI} – 0.1)	V _{CCI}	(V _{CCI} – 0.1)	V _{CCI}	V
	$(I_{OH} = -8 \text{ mA}) \text{ (TTL)}$	2.4	V_{CCI}			
	$(I_{OH} = -6 \text{ mA}) \text{ (TTL)}$			2.4	V_{CCI}	
V _{OL}	(I _{OL} = 20 μA) (CMOS)		0.10			V
	(I _{OL} = 12 mA) (TTL)		0.50			
	$(I_{OL} = 8 \text{ mA}) \text{ (TTL)}$				0.50	
V_{IL}			8.0		0.8	V
V_{IH}		2.0		2.0		V
t _R , t _F	Input Transition Time t _R , t _F		50		50	ns
C _{IO}	C _{IO} I/O Capacitance		10		10	pF
I _{CC}	Standby Current, I _{CC}		4.0		4.0	mA
$I_{CC(D)}$	I _{CC(D)} I _{Dynamic} V _{CC} Supply Current	See '	'Evaluating F	ower in SX Device	es" on page ´	1-16.

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A54SX16P DC Specifications (3.3 V PCI Operation)

Table 1-8 • A54SX16P DC Specifications (3.3 V PCI Operation)

Symbol	Parameter	Condition	Min.	Max.	Units
V_{CCA}	Supply Voltage for Array		3.0	3.6	V
V_{CCR}	Supply Voltage required for Internal Biasing		3.0	3.6	V
V_{CCI}	Supply Voltage for I/Os		3.0	3.6	V
V_{IH}	Input High Voltage		0.5V _{CC}	$V_{CC} + 0.5$	V
V_{IL}	Input Low Voltage		-0.5	0.3V _{CC}	V
I _{IPU}	Input Pull-up Voltage ¹		0.7V _{CC}		V
I _{IL}	Input Leakage Current ²	$0 < V_{IN} < V_{CC}$		±10	μΑ
V_{OH}	Output High Voltage	I _{OUT} = -500 μA	0.9V _{CC}		V
V_{OL}	Output Low Voltage	I _{OUT} = 1500 μA		0.1V _{CC}	V
C _{IN}	Input Pin Capacitance ³			10	pF
C _{CLK}	CLK Pin Capacitance		5	12	pF
C _{IDSEL}	IDSEL Pin Capacitance ⁴			8	pF

Notes:

- 1. This specification should be guaranteed by design. It is the minimum voltage to which pull-up resistors are calculated to pull a floated network. Applications sensitive to static power utilization should assure that the input buffer is conducting minimum current at this input voltage.
- 2. Input leakage currents include hi-Z output leakage for all bidirectional buffers with tristate outputs.
- 3. Absolute maximum pin capacitance for a PCI input is 10 pF (except for CLK).
- 4. Lower capacitance on this input-only pin allows for non-resistive coupling to AD[xx].

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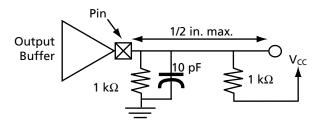
A54SX16P AC Specifications (3.3 V PCI Operation)

Table 1-9 • A54SX16P AC Specifications (3.3 V PCI Operation)

Symbol	Parameter	Condition	Min.	Max.	Units
	Switching Current High	$0 < V_{OUT} \le 0.3 V_{CC}^{1}$			mA
		$0.3V_{CC} \le V_{OUT} < 0.9V_{CC}^{1}$	–12V _{CC}		mA
I _{OH(AC)}		$0.7V_{CC} < V_{OUT} < V_{CC}^{1, 2}$	-17.1 + (V _{CC} - V _{OUT})	EQ 1-3 on page 1-14	
	(Test Point)	$V_{OUT} = 0.7V_{CC}^2$		-32V _{CC}	mA
	Switching Current High	$V_{CC} > V_{OUT} \ge 0.6 V_{CC}^{1}$			mA
1		$0.6V_{CC} > V_{OUT} > 0.1V_{CC}^{1}$	16V _{CC}		mA
I _{OL(AC)}		$0.18V_{CC} > V_{OUT} > 0^{1, 2}$	26.7V _{OUT}	EQ 1-4 on page 1-14	mA
	(Test Point)	$V_{OUT} = 0.18V_{CC}^2$		38V _{CC}	
I _{CL}	Low Clamp Current	$-3 < V_{IN} \le -1$	-25 + (V _{IN} + 1)/0.015		mA
I _{CH}	High Clamp Current	$-3 < V_{IN} \le -1$	25 + (V _{IN} – V _{OUT} – 1)/0.015		mA
slew _R	Output Rise Slew Rate ³	0.2V _{CC} to 0.6V _{CC} load	1	4	V/ns
slew _F	Output Fall Slew Rate ³	0.6V _{CC} to 0.2V _{CC} load	1	4	V/ns

Notes:

- 1. Refer to the V/I curves in Figure 1-10 on page 1-14. Switching current characteristics for REQ# and GNT# are permitted to be one half of that specified here; i.e., half size output drivers may be used on these signals. This specification does not apply to CLK and RST# which are system outputs. "Switching Current High" specification are not relevant to SERR#, INTA#, INTB#, INTC#, and INTD# which are open drain outputs.
- 2. Maximum current requirements must be met as drivers pull beyond the last step voltage. Equations defining these maximums (C and D) are provided with the respective diagrams in Figure 1-10 on page 1-14. The equation defined maxima should be met by design. In order to facilitate component testing, a maximum current test point is defined for each side of the output driver.
- 3. This parameter is to be interpreted as the cumulative edge rate across the specified range, rather than the instantaneous rate at any point within the transition range. The specified load (diagram below) is optional; i.e., the designer may elect to meet this parameter with an unloaded output per the latest revision of the PCI Local Bus Specification. However, adherence to both maximum and minimum parameters is required (the maximum is no longer simply a guideline). Rise slew rate does not apply to open drain outputs.





Power-Up Sequencing

Table 1-10 • Power-Up Sequencing

V _{CCA}	V _{CCR}	V _{CCI}	Power-Up Sequence	Comments
A54SX08, A545	SX16, A54SX32			
3.3 V	5.0 V	3.3 V	5.0 V First 3.3 V Second	No possible damage to device
			3.3 V First 5.0 V Second	Possible damage to device
A54SX16P				
3.3 V	3.3 V	3.3 V	3.3 V Only	No possible damage to device
3.3 V	5.0 V	3.3 V	5.0 V First 3.3 V Second	No possible damage to device
			3.3 V First 5.0 V Second	Possible damage to device
3.3 V	5.0 V	5.0 V	5.0 V First 3.3 V Second	No possible damage to device
			3.3 V First 5.0 V Second	No possible damage to device

Note: No inputs should be driven (high or low) before completion of power-up.

Power-Down Sequencing

Table 1-11 • Power-Down Sequencing

V _{CCA}	V _{CCR}	V _{CCI}	Power-Down Sequence	Comments
A54SX08, A54S	X16, A54SX32			_
3.3 V	5.0 V	3.3 V	5.0 V First 3.3 V Second	Possible damage to device
			3.3 V First 5.0 V Second	No possible damage to device
A54SX16P			•	_
3.3 V	3.3 V	3.3 V	3.3 V Only	No possible damage to device
3.3 V	5.0 V	3.3 V	5.0 V First 3.3 V Second	Possible damage to device
			3.3 V First 5.0 V Second	No possible damage to device
3.3 V	5.0 V	5.0 V	5.0 V First 3.3 V Second	No possible damage to device
			3.3 V First 5.0 V Second	No possible damage to device

Note: No inputs should be driven (high or low) after the beginning of the power-down sequence.

Step 1: Define Terms Used in Formula

	V_{CCA}	3.3
Module		
Number of logic modules switching at f_m (Used 50%)	m	264
Average logic modules switching rate f_m (MHz) (Guidelines: f/10)	f _m	20
Module capacitance C _{EQM} (pF)	C_{EQM}	4.0
Input Buffer		
Number of input buffers switching at f_n	n	1
Average input switching rate f _n (MHz) (Guidelines: f/5)	f _n	40
Input buffer capacitance C _{EQI} (pF)	C_{EQI}	3.4
Output Buffer		
Number of output buffers switching at f_p	p	1
Average output buffers switching rate fp(MHz) (Guidelines: f/10)	f_p	20
Output buffers buffer capacitance C _{EQO} (pF)	C_{EQO}	4.7
Output Load capacitance C _L (pF)	C_L	35
RCLKA		
Number of Clock loads q ₁	q_1	528
Capacitance of routed array clock (pF)	C_{EQCR}	1.6
Average clock rate (MHz)	f_{q1}	200
Fixed capacitance (pF)	r ₁	138
RCLKB		
Number of Clock loads q ₂	q_2	0
Capacitance of routed array clock (pF)	C_{EQCR}	1.6
Average clock rate (MHz)	f_{q2}	0
Fixed capacitance (pF)	r ₂	138
HCLK		
Number of Clock loads	s ₁	0
Variable capacitance of dedicated array clock (pF)	C_{EQHV}	0.61 5
Fixed capacitance of dedicated array clock (pF)	C_{EQHF}	96
Average clock rate (MHz)	f_{s1}	0

Step 2: Calculate Dynamic Power Consumption

$V_{CCA} \times V_{CCA}$	10.89
$m \times f_m \times C_{EQM}$	0.02112
$n \times f_n \times C_{EQI}$	0.000136
$p \times f_p \times (C_{EQO} + C_L)$	0.000794
$0.5 (q_1 \times C_{EQCR} \times f_{q1}) + (r_1 \times f_{q1})$	0.11208
$0.5(q_2 \times C_{EQCR} \times f_{q2}) + (r_2 \times f_{q2})$	0
$0.5 (s_1 \times C_{EQHV} \times f_{s1}) + (C_{EQHF} \times f_{s1})$	0
$P_{AC} = 1.461 \text{ W}$	

Step 3: Calculate DC Power Dissipation DC Power Dissipation

$$\begin{split} P_{DC} &= (I_{standby}) \times V_{CCA} + (I_{standby}) \times V_{CCR} + (I_{standby}) \times \\ V_{CCI} &+ X \times V_{OL} \times I_{OL} + Y(V_{CCI} - V_{OH}) \times V_{OH} \end{split}$$

EQ 1-12

For a rough estimate of DC Power Dissipation, only use $P_{DC} = (I_{standby}) \times V_{CCA}$. The rest of the formula provides a very small number that can be considered negligible.

$$P_{DC} = (I_{standby}) \times V_{CCA}$$

 $P_{DC} = .55 \text{ mA} \times 3.3 \text{ V}$
 $P_{DC} = 0.001815 \text{ W}$

Step 4: Calculate Total Power Consumption

$$P_{Total} = P_{AC} + P_{DC}$$

 $P_{Total} = 1.461 + 0.001815$
 $P_{Total} = 1.4628 W$

Step 5: Compare Estimated Power Consumption against Characterized Power Consumption

The estimated total power consumption for this design is 1.46 W. The characterized power consumption for this design at 200 MHz is 1.0164 W.

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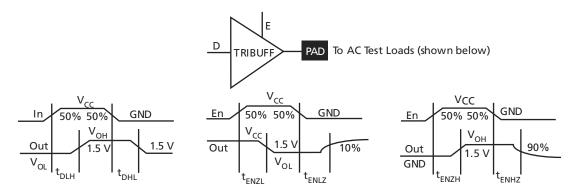


Figure 1-13 • Output Buffer Delays

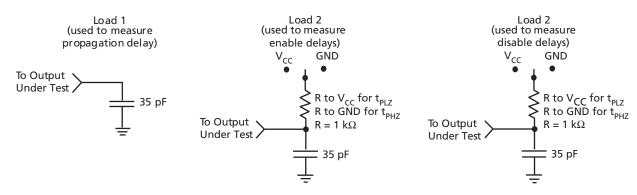


Figure 1-14 • AC Test Loads



Figure 1-15 • Input Buffer Delays

Figure 1-16 • C-Cell Delays

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A54SX08 Timing Characteristics

Table 1-17 • A54SX08 Timing Characteristics (Worst-Case Commercial Conditions, V_{CCR} = 4.75 V, V_{CCA}, V_{CCI} = 3.0 V, T_J = 70°C)

		'-3' 9	Speed	'-2' 9	peed	'-1' !	Speed	'Std' Speed		
Parameter	Description	Min.	Мах.	Min.	Мах.	Min.	Мах.	Min.	Мах.	Units
C-Cell Prop	agation Delays ¹									
t _{PD}	Internal Array Module		0.6		0.7		8.0		0.9	ns
Predicted R	Routing Delays ²									
t _{DC}	FO = 1 Routing Delay, Direct Connect		0.1		0.1		0.1		0.1	ns
t_{FC}	FO = 1 Routing Delay, Fast Connect		0.3		0.4		0.4		0.5	ns
t _{RD1}	FO = 1 Routing Delay		0.3		0.4		0.4		0.5	ns
t _{RD2}	FO = 2 Routing Delay		0.6		0.7		8.0		0.9	ns
t _{RD3}	FO = 3 Routing Delay		8.0		0.9		1.0		1.2	ns
t _{RD4}	FO = 4 Routing Delay		1.0		1.2		1.4		1.6	ns
t _{RD8}	FO = 8 Routing Delay		1.9		2.2		2.5		2.9	ns
t _{RD12}	FO = 12 Routing Delay		2.8		3.2		3.7		4.3	ns
R-Cell Timi	ng									
t _{RCO}	Sequential Clock-to-Q		8.0		1.1		1.2		1.4	ns
t_{CLR}	Asynchronous Clear-to-Q		0.5		0.6		0.7		8.0	ns
t _{PRESET}	Asynchronous Preset-to-Q		0.7		8.0		0.9		1.0	ns
t_{SUD}	Flip-Flop Data Input Set-Up	0.5		0.5		0.7		0.8		ns
t_{HD}	Flip-Flop Data Input Hold	0.0		0.0		0.0		0.0		ns
t _{WASYN}	Asynchronous Pulse Width	1.4		1.6		1.8		2.1		ns
Input Mod	ule Propagation Delays									
t _{INYH}	Input Data Pad-to-Y HIGH		1.5		1.7		1.9		2.2	ns
t _{INYL}	Input Data Pad-to-Y LOW		1.5		1.7		1.9		2.2	ns
Input Mod	ule Predicted Routing Delays ²									
t _{IRD1}	FO = 1 Routing Delay		0.3		0.4		0.4		0.5	ns
t _{IRD2}	FO = 2 Routing Delay		0.6		0.7		8.0		0.9	ns
t _{IRD3}	FO = 3 Routing Delay		0.8		0.9		1.0		1.2	ns
t _{IRD4}	FO = 4 Routing Delay		1.0		1.2		1.4		1.6	ns
t _{IRD8}	FO = 8 Routing Delay		1.9		2.2		2.5		2.9	ns
t _{IRD12}	FO = 12 Routing Delay		2.8		3.2		3.7		4.3	ns

Note:

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^{1.} For dual-module macros, use t_{PD} + t_{RD1} + t_{PDn} , t_{RCO} + t_{RD1} + t_{PDn} , or t_{PD1} + t_{RD1} + t_{SUD} , whichever is appropriate.

^{2.} Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual worst-case performance. Post-route timing is based on actual routing delay measurements performed on the device prior to shipment.

Table 1-20 • A54SX32 Timing Characteristics (Continued)
(Worst-Case Commercial Conditions, V_{CCR}= 4.75 V, V_{CCA}, V_{CCI} = 3.0 V, T_J = 70°C)

		'-3' 9	Speed	'-2' \$	Speed	'-1' 9	peed	'Std'	Speed	
Parameter	Description	Min.	Мах.	Min.	Мах.	Min.	Мах.	Min.	Мах.	Units
Dedicated (Hardwired) Array Clock Network									
t _{HCKH}	Input LOW to HIGH (pad to R-Cell input)		1.9		2.1		2.4		2.8	ns
t _{HCKL}	Input HIGH to LOW (pad to R-Cell input)		1.9		2.1		2.4		2.8	ns
t _{HPWH}	Minimum Pulse Width HIGH	1.4		1.6		1.8		2.1		ns
t _{HPWL}	Minimum Pulse Width LOW	1.4		1.6		1.8		2.1		ns
t _{HCKSW}	Maximum Skew		0.3		0.4		0.4		0.5	ns
t _{HP}	Minimum Period	2.7		3.1		3.6		4.2		ns
f _{HMAX}	Maximum Frequency		350		320		280		240	MHz
Routed Arra	ay Clock Networks									
t _{RCKH}	Input LOW to HIGH (light load) (pad to R-Cell input)		2.4		2.7		3.0		3.5	ns
t _{RCKL}	Input HIGH to LOW (light load) (pad to R-Cell input)		2.4		2.7		3.1		3.6	ns
t _{RCKH}	Input LOW to HIGH (50% load) (pad to R-Cell input)		2.7		3.0		3.5		4.1	ns
t _{RCKL}	Input HIGH to LOW (50% load) (pad to R-Cell input)		2.7		3.1		3.6		4.2	ns
t _{RCKH}	Input LOW to HIGH (100% load) (pad to R-Cell input)		2.7		3.1		3.5		4.1	ns
t _{RCKL}	Input HIGH to LOW (100% load) (pad to R-Cell input)		2.8		3.2		3.6		4.3	ns
t _{RPWH}	Min. Pulse Width HIGH	2.1		2.4		2.7		3.2		ns
t _{RPWL}	Min. Pulse Width LOW	2.1		2.4		2.7		3.2		ns
t _{RCKSW}	Maximum Skew (light load)		0.85		0.98		1.1		1.3	ns
t _{RCKSW}	Maximum Skew (50% load)		1.23		1.4		1.6		1.9	ns
t _{RCKSW}	Maximum Skew (100% load)		1.30		1.5		1.7		2.0	ns
TTL Output Module Timing ³										
t _{DLH}	Data-to-Pad LOW to HIGH		1.6		1.9		2.1		2.5	ns
t _{DHL}	Data-to-Pad HIGH to LOW		1.6		1.9		2.1		2.5	ns
t _{ENZL}	Enable-to-Pad, Z to L		2.1		2.4		2.8		3.2	ns
t _{ENZH}	Enable-to-Pad, Z to H		2.3		2.7		3.1		3.6	ns
t _{ENLZ}	Enable-to-Pad, L to Z		1.4		1.7		1.9		2.2	ns
t _{ENHZ}	Enable-to-Pad, H to Z		1.3		1.5		1.7		2.0	ns

Note:

- 1. For dual-module macros, use t_{PD} + t_{RD1} + t_{PDn} , t_{RCO} + t_{RD1} + t_{PDn} , or t_{PD1} + t_{RD1} + t_{SUD} , whichever is appropriate.
- 2. Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual worst-case performance. Post-route timing is based on actual routing delay measurements performed on the device prior to shipment.

3. Delays based on 35 pF loading, except t_{ENZL} and t_{ENZH} . For t_{ENZL} and t_{ENZH} the loading is 5 pF.

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208-Pin PQFP

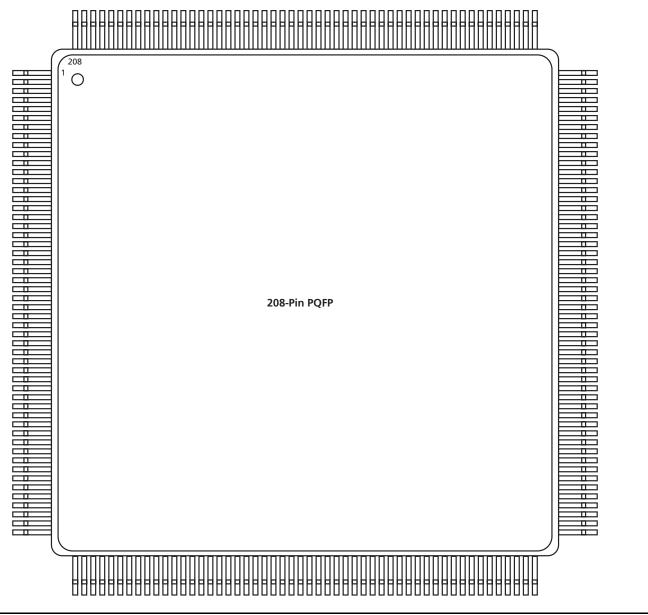


Figure 2-2 • 208-Pin PQFP (Top View)

Note

For Package Manufacturing and Environmental information, visit the Package Resource center at http://www.actel.com/products/rescenter/package/index.html.

144-Pin TQFP

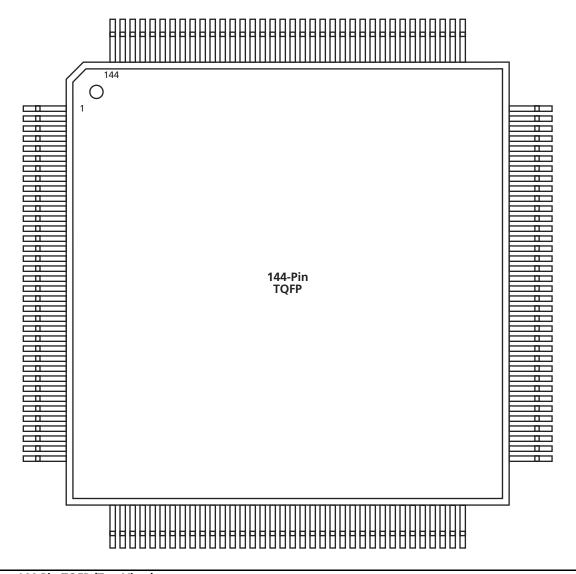


Figure 2-3 • 144-Pin TQFP (Top View)

Note

For Package Manufacturing and Environmental information, visit the Package Resource center at http://www.actel.com/products/rescenter/package/index.html.



176-Pin TQFP			
Pin Number	A54SX08 Function	A54SX16, A54SX16P Function	A54SX32 Function
1	GND	GND	GND
2	TDI, I/O	TDI, I/O	TDI, I/O
3	NC	1/0	I/O
4	I/O	1/0	I/O
5	I/O	1/0	I/O
6	I/O	1/0	I/O
7	I/O	1/0	I/O
8	I/O	1/0	I/O
9	I/O	I/O	I/O
10	TMS	TMS	TMS
11	V _{CCI}	V _{CCI}	V _{CCI}
12	NC	I/O	I/O
13	I/O	I/O	I/O
14	I/O	1/0	I/O
15	I/O	I/O	I/O
16	I/O	I/O	I/O
17	I/O	I/O	I/O
18	I/O	I/O	I/O
19	I/O	I/O	I/O
20	I/O	1/0	I/O
21	GND	GND	GND
22	V _{CCA}	V _{CCA}	V _{CCA}
23	GND	GND	GND
24	I/O	I/O	I/O
25	I/O	I/O	I/O
26	I/O	I/O	I/O
27	I/O	I/O	I/O
28	I/O	I/O	I/O
29	I/O	I/O	I/O
30	I/O	I/O	I/O
31	I/O	I/O	I/O
32	V _{CCI}	V _{CCI}	V _{CCI}
33	V _{CCA}	V _{CCA}	V _{CCA}
34	I/O	1/0	1/0

176-Pin TQFP			
Pin Number	A54SX08 Function	A54SX16, A54SX16P Function	A54SX32 Function
35	I/O	1/0	1/0
36	I/O	I/O	1/0
37	I/O	1/0	I/O
38	I/O	I/O	1/0
39	I/O	I/O	1/0
40	NC	I/O	1/0
41	I/O	I/O	1/0
42	NC	I/O	I/O
43	I/O	I/O	1/0
44	GND	GND	GND
45	I/O	I/O	I/O
46	I/O	I/O	1/0
47	I/O	I/O	1/0
48	I/O	I/O	I/O
49	I/O	I/O	I/O
50	I/O	I/O	1/0
51	I/O	1/0	1/0
52	V _{CCI}	V _{CCI}	V _{CCI}
53	I/O	1/0	1/0
54	NC	1/0	1/0
55	I/O	1/0	1/0
56	I/O	1/0	1/0
57	NC	1/0	1/0
58	I/O	1/0	1/0
59	I/O	1/0	1/0
60	I/O	1/0	1/0
61	1/0	1/0	1/0
62	1/0	1/0	I/O
63	1/0	I/O	1/0
64	PRB, I/O	PRB, I/O	PRB, I/O
65	GND	GND	GND
66	V _{CCA}	V _{CCA}	V _{CCA}
67	V_{CCR}	V_{CCR}	V_{CCR}
68	I/O	1/0	I/O

176-Pin TQFP			
Pin Number	A54SX08 Function	A54SX16, A54SX16P Function	A54SX32 Function
69	HCLK	HCLK	HCLK
70	I/O	I/O	I/O
71	I/O	1/0	I/O
72	I/O	I/O	I/O
73	I/O	I/O	I/O
74	I/O	I/O	I/O
75	I/O	I/O	I/O
76	I/O	I/O	I/O
77	I/O	I/O	I/O
78	I/O	I/O	I/O
79	NC	1/0	I/O
80	I/O	1/0	I/O
81	NC	1/0	I/O
82	V _{CCI}	V _{CCI}	V _{CCI}
83	I/O	I/O	I/O
84	I/O	I/O	I/O
85	I/O	1/0	I/O
86	I/O	1/0	I/O
87	TDO, I/O	TDO, I/O	TDO, I/O
88	I/O	I/O	I/O
89	GND	GND	GND
90	NC	1/0	I/O
91	NC	I/O	I/O
92	I/O	I/O	I/O
93	I/O	1/0	I/O
94	I/O	I/O	I/O
95	I/O	I/O	I/O
96	I/O	I/O	I/O
97	I/O	I/O	I/O
98	V_{CCA}	V _{CCA}	V_{CCA}
99	V _{CCI}	V _{CCI}	V _{CCI}
100	I/O	I/O	I/O
101	I/O	I/O	I/O
102	I/O	1/0	I/O

176-Pin TQFP			
Pin Number	A54SX08 Function	A54SX16, A54SX16P Function	A54SX32 Function
103	1/0	1/0	I/O
104	I/O	1/0	1/0
105	I/O	1/0	1/0
106	I/O	1/0	I/O
107	I/O	I/O	1/0
108	GND	GND	GND
109	V_{CCA}	V_{CCA}	V_{CCA}
110	GND	GND	GND
111	I/O	I/O	1/0
112	I/O	I/O	1/0
113	I/O	I/O	1/0
114	I/O	I/O	I/O
115	I/O	I/O	1/0
116	I/O	I/O	1/0
117	I/O	I/O	I/O
118	NC	I/O	1/0
119	I/O	I/O	1/0
120	NC	1/0	I/O
121	NC	1/0	I/O
122	V_{CCA}	V _{CCA}	V_{CCA}
123	GND	GND	GND
124	V _{CCI}	V _{CCI}	V _{CCI}
125	I/O	I/O	1/0
126	I/O	I/O	1/0
127	I/O	I/O	1/0
128	I/O	I/O	1/0
129	I/O	I/O	1/0
130	I/O	I/O	1/0
131	NC	I/O	I/O
132	NC	I/O	1/0
133	GND	GND	GND
134	I/O	I/O	I/O
135	I/O	I/O	I/O
136	I/O	1/0	I/O

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100-Pin VQFP			
Pin Number	A54SX08 Function	A54SX16, A54SX16P Function	
1	GND	GND	
2	TDI, I/O	TDI, I/O	
3	1/0	I/O	
4	I/O	I/O	
5	1/0	I/O	
6	I/O	I/O	
7	TMS	TMS	
8	V _{CCI}	V _{CCI}	
9	GND	GND	
10	I/O	I/O	
11	I/O	I/O	
12	I/O	I/O	
13	1/0	I/O	
14	1/0	I/O	
15	I/O	I/O	
16	I/O	I/O	
17	I/O	I/O	
18	I/O	I/O	
19	I/O	I/O	
20	V _{CCI}	V _{CCI}	
21	I/O	I/O	
22	I/O	I/O	
23	I/O	I/O	
24	I/O	I/O	
25	I/O	I/O	
26	I/O	I/O	
27	I/O	I/O	
28	I/O	I/O	
29	I/O	I/O	
30	I/O	I/O	
31	I/O	I/O	
32	I/O	1/0	
33	I/O	1/0	
34	PRB, I/O	PRB, I/O	

100-Pin VQFP			
Pin Number	A54SX08 Function	A54SX16, A54SX16P Function	
35	V_{CCA}	V_{CCA}	
36	GND	GND	
37	V_{CCR}	V_{CCR}	
38	1/0	I/O	
39	HCLK	HCLK	
40	1/0	I/O	
41	1/0	I/O	
42	1/0	I/O	
43	1/0	I/O	
44	V _{CCI}	V _{CCI}	
45	1/0	I/O	
46	1/0	I/O	
47	1/0	I/O	
48	1/0	I/O	
49	TDO, I/O	TDO, I/O	
50	1/0	I/O	
51	GND	GND	
52	1/0	I/O	
53	1/0	I/O	
54	1/0	I/O	
55	1/0	I/O	
56	I/O	I/O	
57	V_{CCA}	V_{CCA}	
58	V _{CCI}	V _{CCI}	
59	1/0	I/O	
60	I/O	I/O	
61	I/O	I/O	
62	I/O	I/O	
63	I/O	I/O	
64	I/O	I/O	
65	I/O	I/O	
66	I/O	I/O	
67	V_{CCA}	V _{CCA}	
68	GND	GND	

100-Pin VQFP		
Pin Number	A545X08 Function	A54SX16, A54SX16P Function
69	GND	GND
70	I/O	1/0
71	I/O	1/0
72	I/O	1/0
73	I/O	1/0
74	I/O	1/0
75	1/0	1/0
76	I/O	1/0
77	I/O	1/0
78	I/O	I/O
79	I/O	1/0
80	I/O	I/O
81	1/0	1/0
82	V _{CCI}	V _{CCI}
83	1/0	I/O
84	I/O	I/O
85	I/O	1/0
86	I/O	1/0
87	CLKA	CLKA
88	CLKB	CLKB
89	V_{CCR}	V_{CCR}
90	V_{CCA}	V_{CCA}
91	GND	GND
92	PRA, I/O	PRA, I/O
93	I/O	I/O
94	I/O	1/0
95	1/0	1/0
96	1/0	1/0
97	1/0	1/0
98	1/0	1/0
99	1/0	1/0
100	TCK, I/O	TCK, I/O

329-Pin PBGA			
Pin Number	A54SX32 Function		
A1	GND		
A2	GND		
А3	V _{CCI}		
A4	NC		
A5	I/O		
A6	I/O		
A7	V _{CCI}		
A8	NC		
A9	I/O		
A10	I/O		
A11	I/O		
A12	I/O		
A13	CLKB		
A14	I/O		
A15	I/O		
A16	I/O		
A17	I/O		
A18	I/O		
A19	I/O		
A20	I/O		
A21	NC		
A22	V _{CCI}		
A23	GND		
AA1	V _{CCI}		
AA2	I/O		
AA3	GND		
AA4	I/O		
AA5	1/0		
AA6	I/O		
AA7	I/O		
AA8	I/O		
AA9	I/O		
AA10	I/O		
AA11	I/O		
AA12	1/0		

329-Pin PBGA			
Pin Number	A54SX32 Function		
AA13	1/0		
AA14	I/O		
AA15	I/O		
AA16	I/O		
AA17	1/0		
AA18	I/O		
AA19	I/O		
AA20	TDO, I/O		
AA21	V _{CCI}		
AA22	1/0		
AA23	V _{CCI}		
AB1	1/0		
AB2	GND		
AB3	1/0		
AB4	1/0		
AB5	1/0		
AB6	1/0		
AB7	1/0		
AB8	1/0		
AB9	1/0		
AB10	1/0		
AB11	PRB, I/O		
AB12	1/0		
AB13	HCLK		
AB14	1/0		
AB15	1/0		
AB16	1/0		
AB17	1/0		
AB18	1/0		
AB19	1/0		
AB20	I/O		
AB21	I/O		
AB22	GND		
AB23	1/0		
AC1	GND		

329-Pin PBGA			
Pin Number	A54SX32 Function		
AC2	V _{CCI}		
AC3	NC		
AC4	1/0		
AC5	I/O		
AC6	I/O		
AC7	I/O		
AC8	I/O		
AC9	V _{CCI}		
AC10	I/O		
AC11	I/O		
AC12	I/O		
AC13	I/O		
AC14	I/O		
AC15	NC		
AC16	I/O		
AC17	I/O		
AC18	I/O		
AC19	I/O		
AC20	I/O		
AC21	NC		
AC22	V _{CCI}		
AC23	GND		
B1	V _{CCI}		
B2	GND		
В3	I/O		
В4	I/O		
B5	I/O		
В6	I/O		
В7	I/O		
B8	I/O		
В9	I/O		
B10	I/O		
B11	I/O		
B12	PRA, I/O		
B13	CLKA		

329-Pin PBGA		
Pin Number	A54SX32 Function	
B14	1/0	
B15	1/0	
B16		
	1/0	
B17	1/0	
B18	1/0	
B19	1/0	
B20	I/O	
B21	I/O	
B22	GND	
B23	V _{CCI}	
C1	NC	
C2	TDI, I/O	
C3	GND	
C4	I/O	
C5	I/O	
C6	I/O	
C7	I/O	
C8	I/O	
С9	I/O	
C10	I/O	
C11	I/O	
C12	I/O	
C13	I/O	
C14	I/O	
C15	I/O	
C16	I/O	
C17	I/O	
C18	I/O	
C19	I/O	
C20	I/O	
C21	V _{CCI}	
C22	GND	
C23	NC	
D1	I/O	
D2	I/O	

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144-Pin FBGA

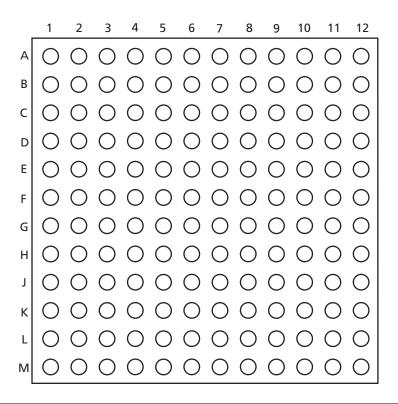


Figure 2-8 • 144-Pin FBGA (Top View)

Note

For Package Manufacturing and Environmental information, visit the Package Resource center at http://www.actel.com/products/rescenter/package/index.html.

Datasheet Information

List of Changes

The following table lists critical changes that were made in the current version of the document.

Previous Version	Changes in Current Version (v3.2)	Page
v3.1	The "Ordering Information" was updated to include RoHS information.	1-ii
(June 2003)	The Product Plan was removed since all products have been released.	N/A
	Information concerning the TRST pin in the "Probe Circuit Control Pins" section was removed.	1-6
	The "Dedicated Test Mode" section is new.	1-6
	The "Programming" section is new.	1-7
	A note was added to the "Power-Up Sequencing" table.	1-15
	A note was added to the "Power-Down Sequencing" table. The 3.3 V comments were updated for the following devices: A54SX08, A54SX16, A54SX32.	1-15
	U11 and U13 were added to the "313-Pin PBGA" table.	2-17
v3.0.1	Storage temperature in Table 1-3 was updated.	1-7
	Table 1-1 was updated.	1-5

Datasheet Categories

In order to provide the latest information to designers, some datasheets are published before data has been fully characterized. Datasheets are designated as "Product Brief," "Advanced," "Production," and "Datasheet Supplement." The definitions of these categories are as follows:

Product Brief

The product brief is a summarized version of a datasheet (advanced or production) containing general product information. This brief gives an overview of specific device and family information.

Advanced

This datasheet version contains initial estimated information based on simulation, other products, devices, or speed grades. This information can be used as estimates, but not for production.

Unmarked (production)

This datasheet version contains information that is considered to be final.

Datasheet Supplement

The datasheet supplement gives specific device information for a derivative family that differs from the general family datasheet. The supplement is to be used in conjunction with the datasheet to obtain more detailed information and for specifications that do not differ between the two families.

International Traffic in Arms Regulations (ITAR) and Export Administration Regulations (EAR)

The products described in this datasheet are subject to the International Traffic in Arms Regulations (ITAR) or the Export Administration Regulations (EAR). They may require an approved export license prior to their export. An export can include a release or disclosure to a foreign national inside or outside the United States.